

Average gate power dissipation ($T_j=125^\circ\text{C}$)	$P_{G(AV)}$	0.5	W
Peak gate power	P_{GM}	10	W
Peak pulse voltage ($T_j=25^\circ\text{C}$; non-repetitive, off-state; FIG.7)	V_{pp}	2	kV

ORDERING INFORMATION

AC	J	T	8	10	-10	A
AC switch		Triacs	$I_{T(RMS)}:8A$			A:TO-220A(Ins)
JieJie Microelectronics Co., Ltd.			10: I_{GT1-3} 10mA		10: V_{DRM} / V_{RRM} 1000V	

MARKING

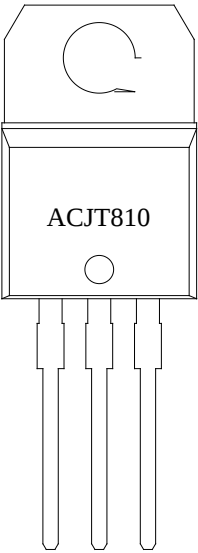


FIG.7 Test circuit for inductive and resistive loads to IEC-61000-4-5 standards



[illegible]